TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SB908

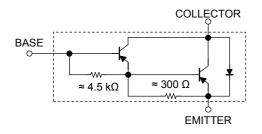
Switching Applications
Hammer Drive, Pulse Motor Drive Applications
Power Amplifier Applications

- High DC current gain: h_{FE} (1) = 2000 (min) (V_{CE} = -2 V, I_{C} = -1 A)
- Low saturation voltage: $V_{CE (sat)} = -1.5 \text{ V (max) (IC} = -3 \text{ A)}$
- Complementary to 2SD1223.

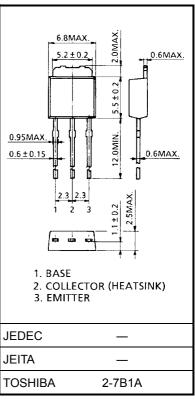
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	-100	٧	
Collector-emitter voltage		V _{CEO}	-80	V	
Emitter-base voltage		V _{EBO}	-5	V	
Collector current		IC	-4	Α	
Base current		ΙΒ	-0.4	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	15		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

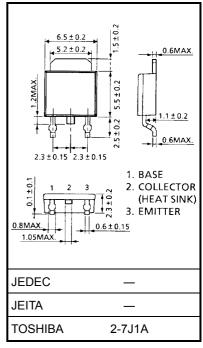
Equivalent Circuit



Unit: mm



Weight: 0.36 g (typ.)

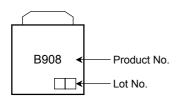


Weight: 0.36 g (typ.)

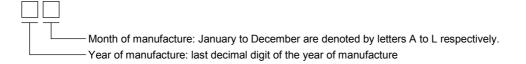
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	ırrent	I _{CBO}	V _{CB} = -100 V, I _E = 0		_	-20	μA
Emitter cut-off curr	rent	I _{EBO}	V _{EB} = -5 V, I _C = 0	-	_	-2.5	mA
Collector-emitter b	reakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-80	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = -2 V, I _C = -1 A	2000	_	_	
		h _{FE (2)}	V _{CE} = -2 V, I _C = -3 A	1000	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = -3 A, I _B = -6 mA	-	_	-1.5	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = -3 A, I _B = -6 mA	-	_	-2.0	V
Switching time S	Turn-on time	t _{on}	OUTPUT $B2$ $B2$ $B2$ $B2$ $B2$ $B2$ $B2$ C C C C C C C	_	0.15	_	
	Storage time	t _{stg}		_	0.80	_	μs
	Fall time	t _f			0.40		

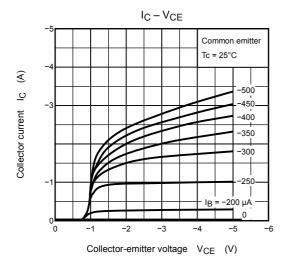
Marking

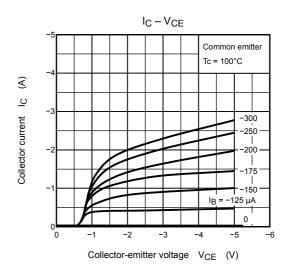


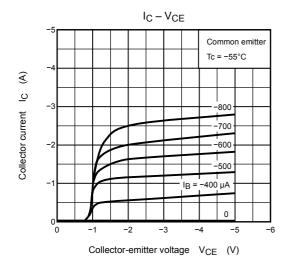
Explanation of Lot No.

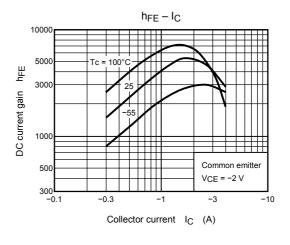


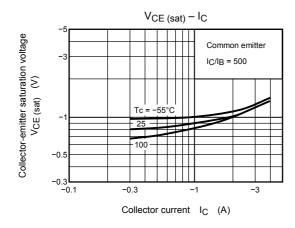
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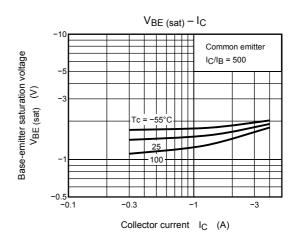




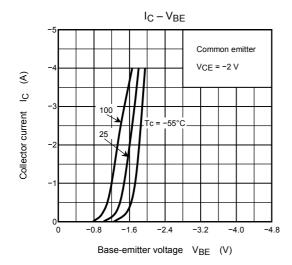


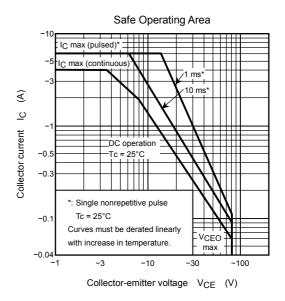


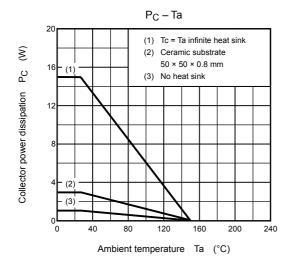




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